

Attorney Docket No. 5308-127DV

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Allen *et al.*

Serial No.: To Be Assigned

Filed: Concurrently Herewith

For: METHODS OF FABRICATING SILICON CARBIDE METAL-
SEMICONDUCTOR FIELD EFFECT TRANSISTORS

Date: November 12, 2003

Mail Stop PATENT APPLICATION
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT

Sir:

Please enter the following Preliminary Amendment before examining the present application.

Amendments to the Title begin on page 2 of this paper.

Amendments to the Specification begin on page 3 of this paper.

Amendments to the Claims are reflected in the listing of claims, which begins on page 4 of this paper.

Remarks begin on page 16 of this paper.

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In the Title:

Please delete the title in all occurrences and substitute the following title
therefor: -- METHODS OF FABRICATING SILICON CARBIDE METAL-
SEMICONDUCTOR FIELD EFFECT TRANSISTORS--.